TPS6208x 采用 2x2 QFN 封装且具有自动切断短路保护功能的 3A 降压转换器

1 特性

- DCS-Control™拓扑技术
- 效率高达 95%
- 自动切断短路保护功能
- 针对轻载效率的省电模式
- 针对最低压降的 100% 占空比
- 输入电压范围 2.5V 至 6.0V
- 17μA 工作静态电流
- 0.8V 至 V_{IN} 可调输出电压
- 1.8V 至 3.3V 固定输出电压
- 输出放电
- 电源正常输出
- 热关断保护
- 采用 2mm × 2mm QFN 封装

2 应用

- 电池供电类 应用
- 负载点
- 处理器电源
- 机械硬盘

3 说明

TPS62085、TPS62086 和 TPS62087 器件是高频同步降压转换器，经优化具有小解决方案尺寸和高效率两大优点。该器件具有 2.5V 至 6.0V 的输入电压范围，支持常见的电池技术。此器件主要用于宽输出电流范围内的高效降压转换。该转换器在中等程度的负载到高负载时运行于脉宽调制 (PWM) 模式，并在轻负载时自动进入省电模式运行，从而在整个负载电流范围内保持高效率。

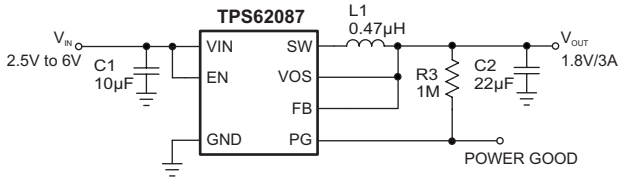
为了满足系统电源轨的需求，内部补偿电路支持 10μF 到 150uF 的宽范围外部输出电容值选项。凭借 DCS-Control 架构，该器件可实现出色的负载瞬态性能和输出稳压精度。这些器件采用 2mm x 2mm QFN 封装。

器件信息(1)

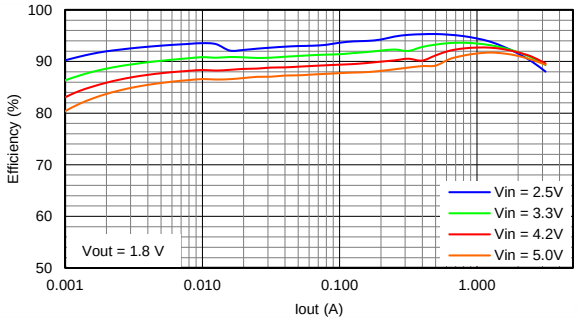
器件型号	封装	封装尺寸（标称值）
TPS62085	VSON (7)	2.00mm x 2.00mm
TPS62086		
TPS62087		

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

4 典型应用电路原理图



典型应用效率



目录

5 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from Original (October 2013) to Revision A **Page**

- 已添加 *ESD 额定值表*，*特性 描述*部分，*器件功能模式*，*应用和实施*部分，*电源相关建议*部分，*布局*部分，*器件和文档支持*部分以及*机械、封装和可订购信息*部分 ... 1

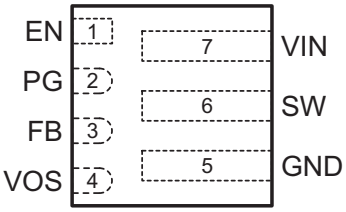
6 Device Options

PART NUMBER(1)	OUTPUT VOLTAGE	PACKAGE MARKING
TPS62085RLT	Adjustable	2085
TPS62086RLT	3.3 V	2086
TPS62087RLT	1.8 V	2087

(1) For detailed ordering information, please check the *机械、封装和可订购信息* section at the end of this datasheet.

7 Pin Configuration and Functions

RLT Package
7-Pin VSON
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
EN	1	IN	Device enable pin. To enable the device, this pin needs to be pulled high. Pulling this pin low disables the device. This pin has a pulldown resistor of typically 400 kΩ when the device is disabled.
FB	3	IN	Feedback pin. For the fixed output voltage versions this pin must be connected to the output voltage.
GND	5		Ground pin.
PG	2	OUT	Power good open drain output pin. The pullup resistor can not be connected to any voltage higher than 6 V. If unused, leave it floating.
SW	6	PWR	Switch pin of the power stage.
VIN	7	PWR	Input voltage pin.
VOS	4	IN	Output voltage sense pin. This pin must be directly connected to the output capacitor.

8 Specifications

8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage at Pins(2)	VIN, FB, VOS, EN, PG	–0.3	7	V
	SW	–0.3	V_{IN} + 0.3	
Temperature	Operating Junction, T_J	–40	150	°C
	Storage, T_{stg}	–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.
(2) All voltage values are with respect to network ground terminal.

8.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 (2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

8.3 Recommended Operating Conditions (1)

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage range	2.5		6	V
I_{SINK_PG}	Sink current at PG pin			1	mA
V_{PG}	Pullup resistor voltage			6	V
T_J	Operating junction temperature	–40		125	°C

(1) Refer to *Application and Implementation* for further information.

8.4 Thermal Information

THERMAL METRIC (1)		TPS6208x RLT [VSON] 7 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	107.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	66.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	17.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	2.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	17.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) 有关传统和新热指标的更多信息，请参见《*半导体和 IC 封装热指标*》应用报告，SPRA953。

8.5 Electrical Characteristics

T_J = –40 °C to 125 °C, and V_{IN} = 3.6 V. Typical values are at T_J = 25 °C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
V_{IN}	Input voltage range		2.5		6	V
I_Q	Quiescent current into VIN	No load, device not switching T_J = –40 °C to 85 °C, V_{IN} = 2.5 V to 5.5 V		17	25	µA
I_{SD}	Shutdown current into VIN	EN = Low, T_J = –40 °C to 85 °C, V_{IN} = 2.5 V to 5.5 V		0.7	5	µA
V_{UVLO}	Undervoltage lockout threshold	V_{IN} falling	2.1	2.2	2.3	V
	Undervoltage lockout hysteresis	V_{IN} rising		200		mV
T_{JSD}	Thermal shutdown threshold	T_J rising		150		°C
	Thermal shutdown hysteresis	T_J falling		20		°C
LOGIC INTERFACE EN						
V_{IH}	High-level input voltage	V_{IN} = 2.5 V to 6.0 V	1.0			V
V_{IL}	Low-level input voltage	V_{IN} = 2.5 V to 6.0 V			0.4	V
$I_{EN,LKG}$	Input leakage current into EN pin	EN = High		0.01	0.16	µA
R_{PD}	Pulldown resistance at EN pin	EN = Low		400		kΩ
SOFT START, POWER GOOD						
t_{SS}	Soft-start time	Time from EN high to 95% of V_{OUT} nominal		0.8		ms
V_{PG}	Power good threshold	V_{OUT} rising, referenced to V_{OUT} nominal	93%	95%	98%	
		V_{OUT} falling, referenced to V_{OUT} nominal	88%	90%	93%	
$V_{PG,OL}$	Low-level output voltage	I_{sink} = 1 mA			0.4	V

Electrical Characteristics (接下页)

T_J = –40 °C to 125 °C, and V_{IN} = 3.6 V. Typical values are at T_J = 25 °C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{PG,LKG}$	Input leakage current into PG pin	V_{PG} = 5.0 V		0.01	0.16	µA
OUTPUT						
V_{OUT}	Output voltage range, TPS62085		0.8		V_{IN}	V
	Output voltage accuracy, TPS62086, TPS62087(1)	I_{OUT} = 1 A, V_{IN} ≥ V_{OUT} + 1 V, PWM mode	–1.0%		1.0%	
		I_{OUT} = 0 A, V_{IN} ≥ V_{OUT} + 1 V, PFM mode	–1.0%		2.1%	
V_{FB}	Feedback regulation voltage(1)(2)	I_{OUT} = 1A , V_{IN} ≥ V_{OUT} + 1 V, PWM mode	792	800	808	mV
		I_{OUT} = 0 A, V_{IN} ≥ V_{OUT} + 1 V, PFM mode	792	800	817	
$I_{FB,LKG}$	Feedback input leakage current	V_{FB} = 1 V		0.01	0.1	µA
R_{DIS}	Output discharge resistor	EN = LOW, V_{OUT} = 1.8 V		260		Ω
	Line regulation	I_{OUT} = 1 A, V_{IN} = 2.5 V to 6.0 V		0.02		%/V
	Load regulation	I_{OUT} = 0.5 A to 3 A		0.16		%/A
POWER SWITCH						
$R_{DS(on)}$	High-side FET ON-resistance	I_{SW} = 500 mA		31	56	mΩ
	Low-side FET ON-resistance	I_{SW} = 500 mA		23	45	mΩ
I_{LIM}	High-side FET switch current limit		3.7	4.6	5.5	A
f_{SW}	PWM switching frequency	I_{OUT} = 1 A		2.4		MHz

(1) For more information, see *Power Save Mode*.
(2) Conditions: L = 0.47 µH, C_{OUT} = 22 µF

8.6 Typical Characteristics

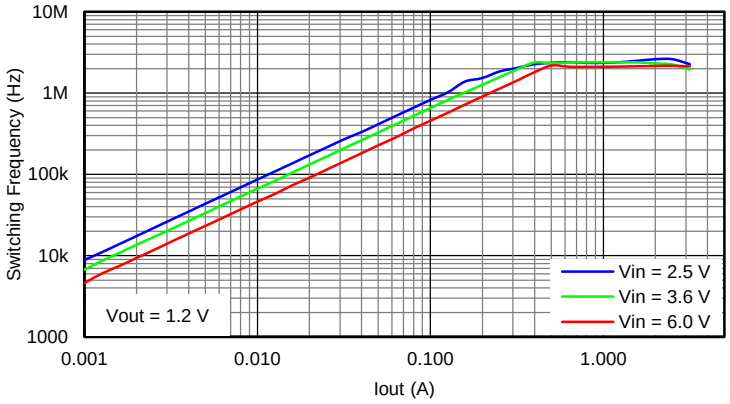


图 1. Switching Frequency

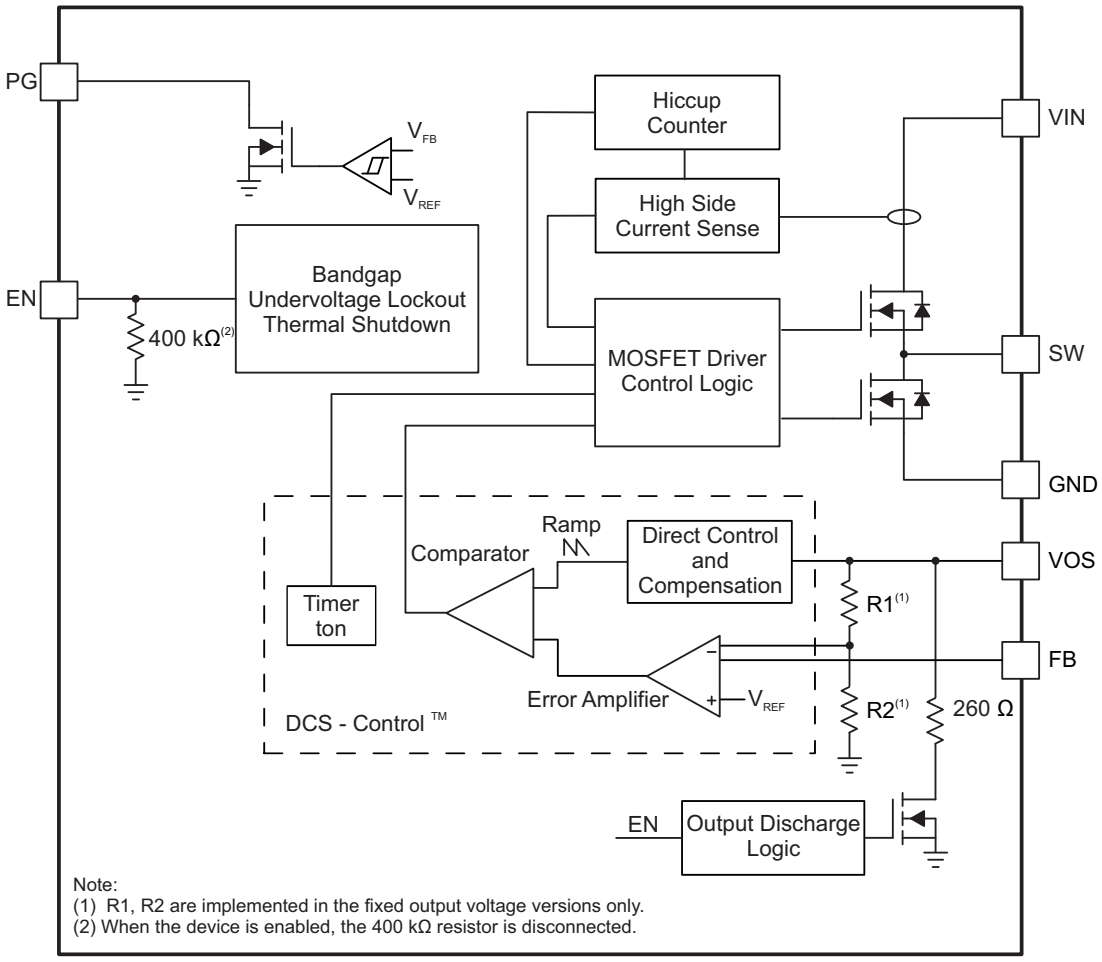
9 Detailed Description

9.1 Overview

The TPS62085, TPS62086, and TPS62087 synchronous step-down converters are based on the DCS-Control (Direct Control with Seamless transition into Power Save Mode) topology. This is an advanced regulation topology that combines the advantages of hysteretic, voltage, and current mode control schemes.

The DCS-Control topology operates in PWM (pulse width modulation) mode for medium to heavy load conditions and in Power Save Mode at light load currents. In PWM mode, the converter operates with its nominal switching frequency of 2.4 MHz, having a controlled frequency variation over the input voltage range. As the load current decreases, the converter enters Power Save Mode, reducing the switching frequency and minimizing the IC quiescent current to achieve high efficiency over the entire load current range. Because DCS-Control supports both operation modes (PWM and PFM) within a single building block, the transition from PWM mode to Power Save Mode is seamless and without effects on the output voltage. Fixed output voltage version provides smallest solution size combined with lowest no load current. The devices offer both excellent DC voltage and superior load transient regulation, combined with very low output voltage ripple, minimizing interference with RF circuits.

9.2 Functional Block Diagram



Note:
(1) R1, R2 are implemented in the fixed output voltage versions only.
(2) When the device is enabled, the 400 kΩ resistor is disconnected.

9.3 Feature Description

9.3.1 Power Save Mode

As the load current decreases, the TPS62085, TPS62086, and TPS62087 enter Power Save Mode operation. During Power Save Mode, the converter operates with reduced switching frequency and with a minimum quiescent current maintaining high efficiency. The power save mode occurs when the inductor current becomes discontinuous. Power Save Mode is based on a fixed on-time architecture, as related in 公式 1. The switching frequency over the whole load current range is also shown in 图 1 for a typical application.

$$t_{ON} = 420\ ns \times \frac{V_{OUT}}{V_{IN}}$$

$$f_{PFM} = \frac{2 \times I_{OUT}}{t_{ON}^2 \times \frac{V_{IN}}{V_{OUT}} \times \frac{V_{IN} - V_{OUT}}{L}} \quad (1)$$

In Power Save Mode, the output voltage rises slightly above the nominal output voltage, as shown in 图 8. This effect is minimized by increasing the output capacitor or inductor value. The output voltage accuracy in PFM operation is reflected in the electrical specification table and given for a 22-µF output capacitor.

9.3.2 100% Duty Cycle Low Dropout Operation

The devices offer low input-to-output voltage difference by entering 100% duty cycle mode. In this mode, the high-side MOSFET switch is constantly turned on and the low-side MOSFET is switched off. This is particularly useful in battery powered applications to achieve the longest operation time by taking full advantage of the whole battery voltage range. The minimum input voltage to maintain output regulation, depending on the load current and output voltage can be calculated as:

$$V_{IN,MIN} = V_{OUT} + I_{OUT,MAX} \times (R_{DS(on)} + R_L) \quad (2)$$

with

- $V_{IN,MIN}$ = Minimum input voltage to maintain an output voltage
- $I_{OUT,MAX}$ = Maximum output current
- $R_{DS(on)}$ = High-side FET ON-resistance
- R_L = Inductor ohmic resistance (DCR)

9.3.3 Soft Start

The TPS62085, TPS62086, and TPS62087 have an internal soft-start circuitry which monotonically ramps up the output voltage and reaches the nominal output voltage during a soft-start time of typically 0.8 ms. This avoids excessive inrush current and creates a smooth output voltage slope. It also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance. The device is able to start into a prebiased output capacitor. The device starts with the applied bias voltage and ramps the output voltage to its nominal value.

9.3.4 Switch Current Limit and Hiccup Short-Circuit Protection

The switch current limit prevents the devices from high inductor current and from drawing excessive current from the battery or input voltage rail. Excessive current might occur with a shorted or saturated inductor or a heavy load or shorted output circuit condition. If the inductor current reaches the threshold I_{LIM}, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current. When this switch current limits is triggered 32 times, the devices stop switching and enable the output discharge. The devices then automatically start a new start-up after a typical delay time of 66 µs has passed. This is named HICCUP short-circuit protection. The devices repeat this mode until the high load condition disappears.

9.3.5 Undervoltage Lockout

To avoid misoperation of the device at low input voltages, an undervoltage lockout (UVLO) is implemented, which shuts down the devices at voltages lower than V_{UVLO} with a hysteresis of 200 mV.

Feature Description (接下页)

9.3.6 Thermal Shutdown

The device goes into thermal shutdown and stops switching when the junction temperature exceeds T_{JSD}. When the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically.

9.4 Device Functional Modes

9.4.1 Enable and Disable

The devices are enabled by setting the EN pin to a logic HIGH. Accordingly, shutdown mode is forced if the EN pin is pulled LOW with a shutdown current of typically 0.7 μA.

In shutdown mode, the internal power switches as well as the entire control circuitry are turned off. An internal resistor of 260 Ω discharges the output through the VOS pin smoothly. The output discharge function also works when thermal shutdown, UVLO, or short-circuit protection are triggered.

An internal pulldown resistor of 400 kΩ is connected to the EN pin when the EN pin is LOW. The pulldown resistor is disconnected when the EN pin is HIGH.

9.4.2 Power Good

The TPS62085, TPS62086, and TPS62087 have a power good output. The power good goes high impedance once the output is above 95% of the nominal voltage, and is driven low once the output voltage falls below typically 90% of the nominal voltage. The PG pin is an open-drain output and is specified to sink up to 1 mA. The power good output requires a pullup resistor connecting to any voltage rail less than 6 V. The power good goes low when the devices are disabled or in thermal shutdown. When the devices are in UVLO, the PG pin is high impedance.

The PG signal can be used for sequencing of multiple rails by connecting it to the EN pin of other converters. Leave the PG pin unconnected when not used.

10 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The TPS62085 is a synchronous step-down converter in which output voltage is adjusted by component selection. The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference. The TPS62086 and TPS62087 devices provide a fixed output voltage which does not need an external resistor divider.

10.2 Typical Application

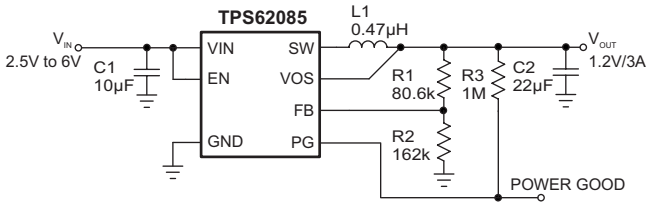


图 2. 1.2-V Output Voltage Application

10.2.1 Design Requirements

For this design example, use the parameters listed in 表 1 as the input parameters.

表 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage	2.5 V to 6 V
Output voltage	1.2 V
Output ripple voltage	<20 mV
Maximum output current	3 A

表 2 lists the components used for the example.

表 2. List of Components

REFERENCE	DESCRIPTION	MANUFACTURER
C1	10 µF, Ceramic capacitor, 6.3 V, X7R, size 0805, GRM21BR71A106ME51L	Murata
C2	22 µF, Ceramic capacitor, 6.3 V, X5R, size 0805, GRM21BR60J226ME39L	Murata
L1	0.47 µH, Power Inductor, size 4 mm × 4 mm × 1.5 mm, XFL4015-471ME	Coilcraft
R1	Depending on the output voltage, 1%, size 0603; 0 Ω for TPS62086, TPS62087	Std
R2	162 kΩ, Chip resistor, 1/16 W, 1%, size 0603; open for TPS62086, TPS62087	Std
R3	1 MΩ, Chip resistor, 1/16 W, 1%, size 0603	Std

10.2.2 Detailed Design Procedure

10.2.2.1 Setting The Output Voltage

The output voltage is set by an external resistor divider according to 公式 3:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R1}{R2}\right) = 0.8\ V \times \left(1 + \frac{R1}{R2}\right) \quad (3)$$

R2 must not be higher than 180 kΩ to achieve high efficiency at light load while providing acceptable noise sensitivity. Lowest operating quiescent current and best output voltage accuracy are achieved with the fixed output voltage versions. For the fixed output voltage versions, the FB pin must be connected to the output.

10.2.2.2 Output Filter Design

The inductor and the output capacitor together provide a low-pass filter. To simplify the selection process, 表 3 outlines possible inductor and capacitor value combinations for most applications.

表 3. Matrix of Output Capacitor and Inductor Combinations

NOMINAL L [µH](1)	NOMINAL C_{OUT} [µF](2)				
	10	22	47	100	150
0.47		+(3)	+	+	+
1	+	+	+	+	+
2.2					

(1) Inductor tolerance and current derating is anticipated. The effective inductance can vary by 20% and –30%.
(2) Capacitance tolerance and bias voltage derating is anticipated. The effective capacitance can vary by 20% and –50%.
(3) Typical application configuration. Other '+' mark indicates recommended filter combinations.

10.2.2.3 Inductor Selection

The main parameter for the inductor selection is the inductor value and then the saturation current of the inductor. To calculate the maximum inductor current under static load conditions, 公式 4 is given.

$$I_{L,MAX} = I_{OUT,MAX} + \frac{\Delta I_L}{2}$$

$$\Delta I_L = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f_{SW}}$$

where

- $I_{OUT,MAX}$ = Maximum output current
- ΔI_L = Inductor current ripple
- f_{SW} = Switching frequency
- L = Inductor value

(4)

TI recommends choosing the saturation current for the inductor 20% to 30% higher than the $I_{L,MAX}$, out of 公式 4. A higher inductor value is also useful to lower ripple current but increases the transient response time as well. The following inductors are recommended to be used in designs.

表 4. List of Recommended Inductors

INDUCTANCE [µH]	CURRENT RATING [A]	DIMENSIONS L × W × H [mm^3]	DC RESISTANCE [mΩ typical]	PART NUMBER
0.47	6.6	4 × 4 × 1.5	7.6	Coilcraft XFL4015-471
0.47	4.7	3.2 × 2.5 × 1.2	21	TOKO DFE322512-R47N
1	5.1	4 × 4 × 2	10.8	Coilcraft XFL4020-102

10.2.2.4 Capacitor Selection

The input capacitor is the low-impedance energy source for the converters which helps to provide stable operation. A low ESR multilayer ceramic capacitor is recommended for best filtering and must be placed between VIN and GND as close as possible to those pins. For most applications, 10 µF is sufficient, though a larger value reduces input current ripple.

The architecture of the TPS62085, TPS62086, and TPS62087 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, TI recommends using X7R or X5R dielectrics. The recommended typical output capacitor value is 22 μF; this capacitance can vary over a wide range as outline in the output filter selection table.

A feed-forward capacitor is not required for device proper operation.

10.2.3 Application Curves

V_{IN} = 3.6 V, V_{OUT} = 1.2 V, T_A = 25 ºC, unless otherwise noted

表 5. Table of Graphs

		FIGURE
Efficiency	TPS62085, V_{OUT} = 0.95 V	图 3
	TPS62085, V_{OUT} = 1.2 V	图 4
	TPS62086, V_{OUT} = 3.3 V	图 5
	TPS62087, V_{OUT} = 1.8 V	图 6
Line Regulation	TPS62085	图 7
Load Regulation	TPS62085	图 8
Switching Frequency	TPS62085	图 1
Waveforms	TPS62085, PWM Operation (Load = 3 A)	图 9
	TPS62085, PFM Operation (Load = 100 mA)	图 10
	TPS62085, Load Sweep (Load = Open to 3 A)	图 11
	TPS62085, Start-Up (Load = 0.47 Ω)	图 12
	TPS62085, Start-Up (Load = Open)	图 13
	TPS62085, Shutdown (Load = 0.47 Ω)	图 14
	TPS62085, Shutdown (Load = Open)	图 15
	TPS62085, Load Transient (Load = 0.5 A to 3 A)	图 16
	TPS62085, Load Transient (Load = 50 mA to 3 A)	图 17
	TPS62085, Output Short-Circuit Protection (Load = 0.47 Ω, Entry)	图 18
	TPS62085, Output Short-Circuit Protection (Load = 0.47 Ω, Recovery)	图 19
	TPS62085, Output Short-Circuit Protection (Load = 0.47 Ω, HICCUP Zoom In)	图 20

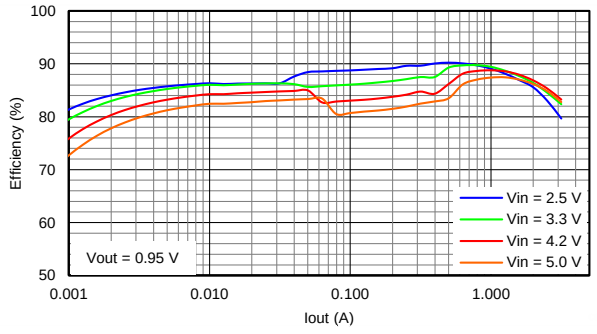


图 3. Efficiency

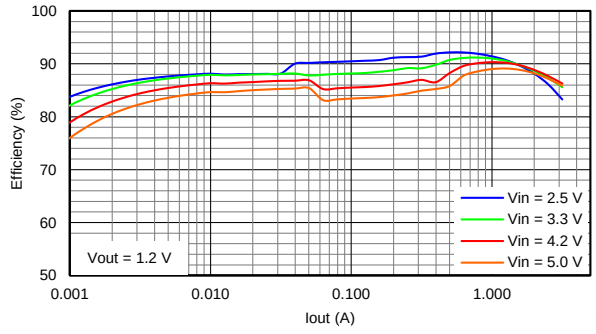


图 4. Efficiency

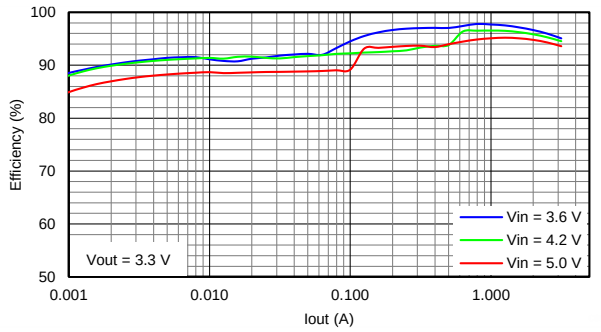


图 5. Efficiency

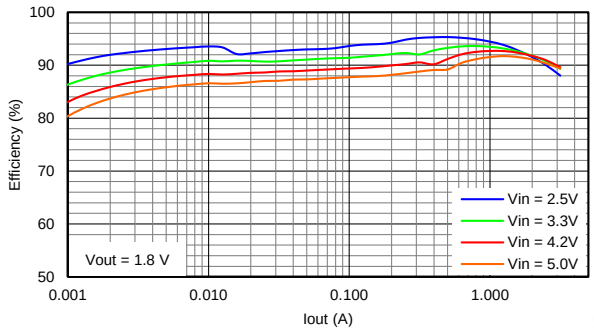


图 6. Efficiency

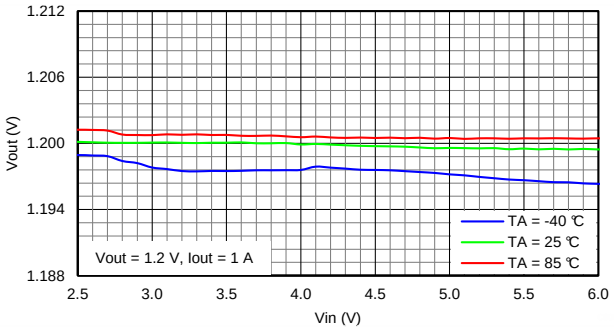


图 7. Line Regulation

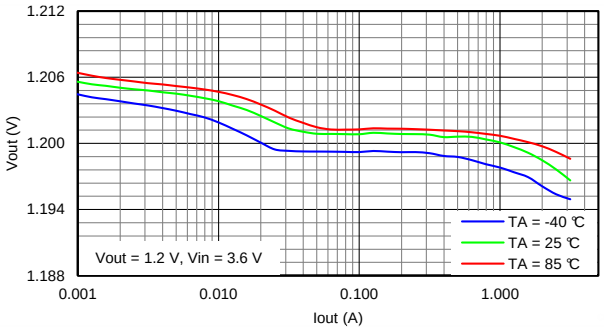


图 8. Load Regulation

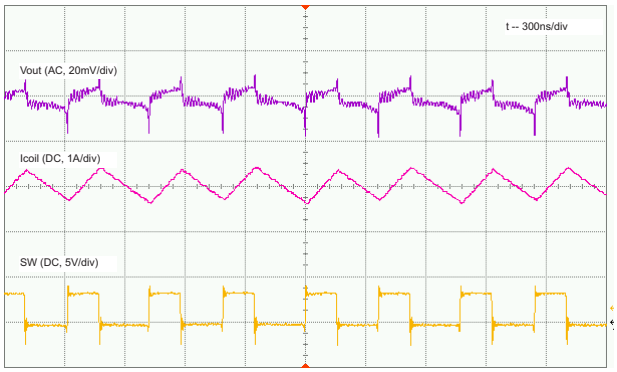


图 9. PWM Operation, Load = 3 A

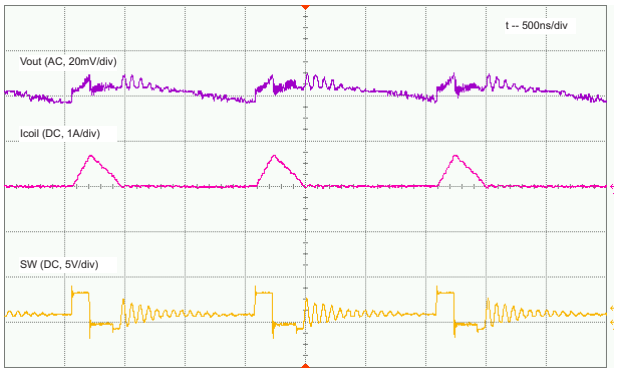


图 10. PFM Operation, Load = 100 mA

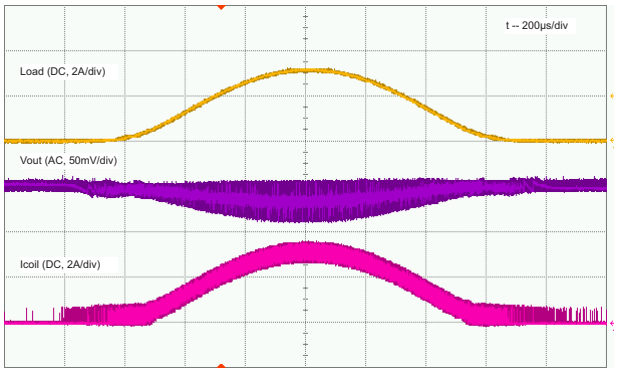


图 11. Load Sweep, Load = Open to 3 A

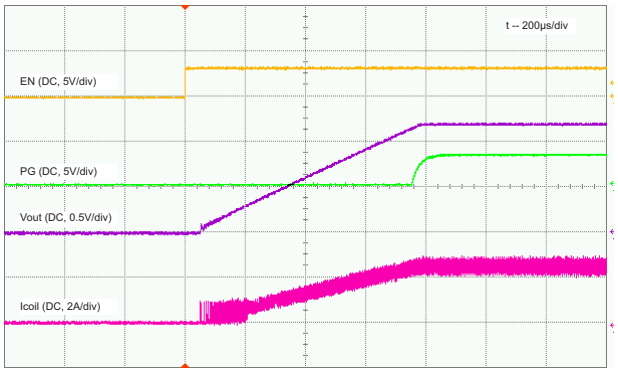


图 12. Start-Up, Load = 0.47 Ω

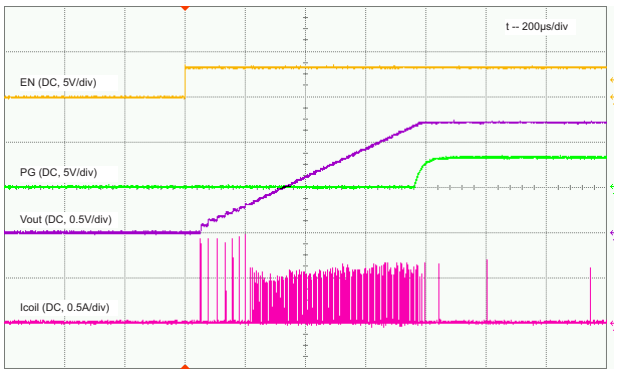


图 13. Start-Up, Load = Open

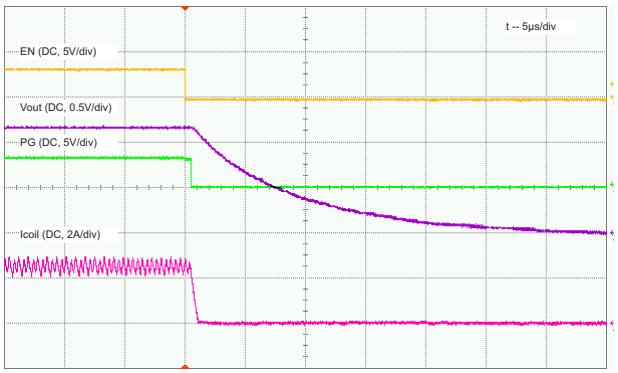


图 14. Shutdown, Load = 0.47 Ω

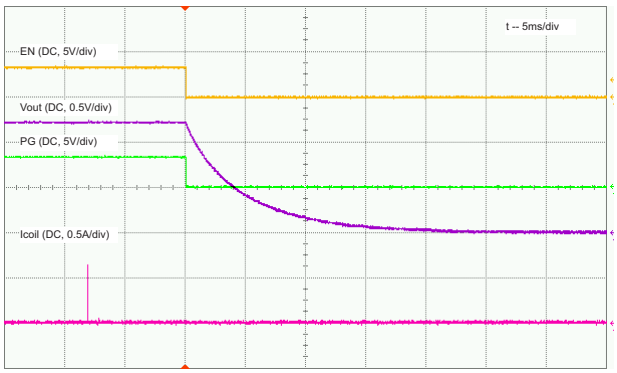


图 15. Shutdown, Load = Open

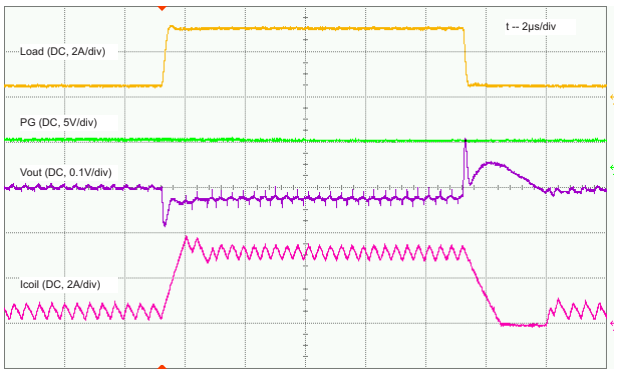


图 16. Load Transient, Load = 0.5 A to 3 A

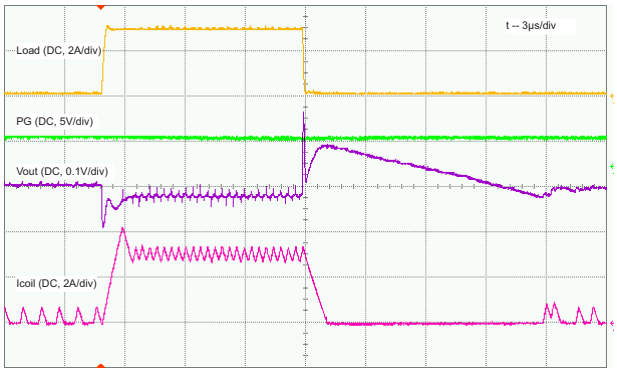


图 17. Load Transient, Load = 50 mA to 3 A

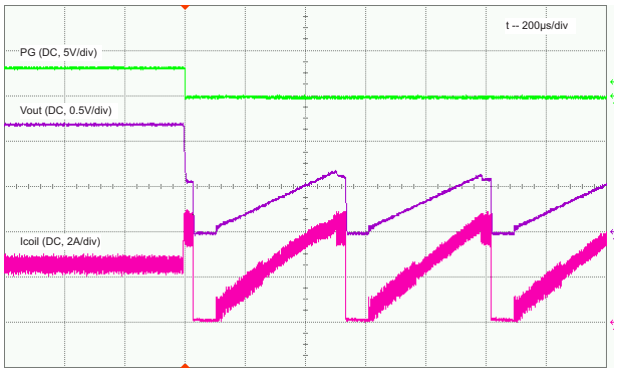


图 18. Output Short-Circuit Protection, Load = 0.47 Ω, Entry

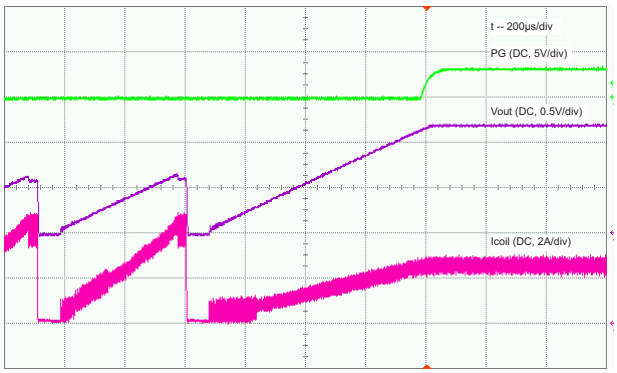


图 19. Output Short-Circuit Protection, Load = 0.47 Ω, Recovery

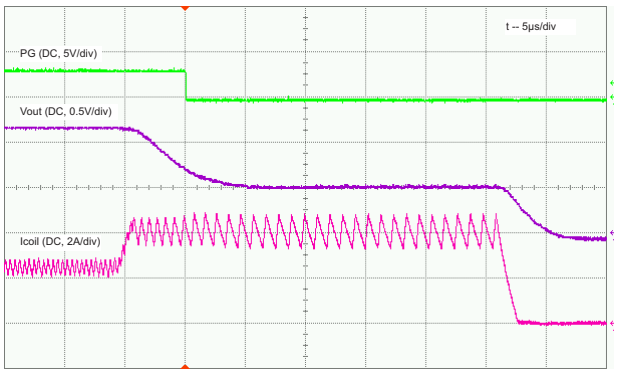


图 20. Output Short-Circuit Protection, Load = 0.47 Ω, HICCUP Zoom In

11 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.5 V to 6 V. Ensure that the input power supply has a sufficient current rating for the application.

12 Layout

12.1 Layout Guidelines

The printed-circuit-board (PCB) layout is an important step to maintain the high performance of the TPS62085, TPS62086, and TPS62087 devices.

The input and output capacitors and the inductor must be placed as close as possible to the IC. This keeps the traces short. Routing these traces direct and wide results in low trace resistance and low parasitic inductance. The low side of the input and output capacitors must be connected directly to the GND pin to avoid a ground potential shift. The sense traces connected to FB and VOS pins are signal traces. Special care must be taken to avoid noise being induced. By a direct routing, parasitic inductance can be kept small. GND layers might be used for shielding. Keep these traces away from SW nodes. See 图 21 for the recommended PCB layout.

12.2 Layout Example

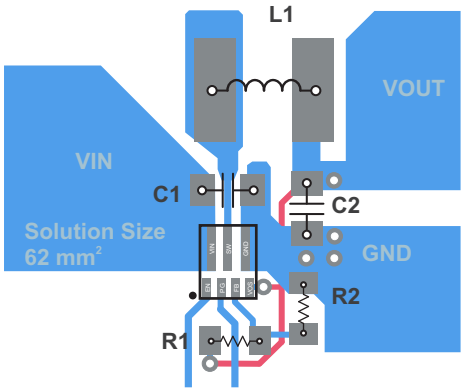


图 21. PCB Layout Recommendation

12.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power dissipation limits of a given component.

Two basic approaches for enhancing thermal performance are:

- Improving the power dissipation capability of the PCB design
- Introducing airflow in the system

The Thermal Data section in the *TPS62085EVM-169 Evaluation Module User's Guide* (SLVU809) provides the thermal metric of the device on the EVM after considering the PCB design of real applications. The big copper planes connecting to the pads of the IC on the PCB improve the thermal performance of the device. For more details on how to use the thermal parameters, see the *Thermal Characteristics Application Notes*, SZZA017 and SPRA953.

13 器件和文档支持

13.1 器件支持

13.1.1 第三方产品免责声明

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13.2 文档支持

13.2.1 相关文档

相关文档如下：

- 《*TPS62085EVM-169 评估模块用户指南*》，SLVU809
- 《*散热特性数据应用手册*》，SZZA017
- 《*散热特性数据应用手册*》，SPRA953

13.3 相关链接

以下表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件，并且可以快速访问样片或购买链接。

表 **6.** 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
TPS62085	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS62086	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS62087	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

13.4 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.5 商标

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13.6 静电放电警告

这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

13.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

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数据转换器	www.ti.com.cn/dataconverters	消费电子	www.ti.com/consumer-apps
DLP® 产品	www.dlp.com	能源	www.ti.com/energy
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接口	www.ti.com.cn/interface	安防应用	www.ti.com.cn/security
逻辑	www.ti.com.cn/logic	汽车电子	www.ti.com.cn/automotive
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RFID 系统	www.ti.com.cn/rfidsys		
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无线连通性	www.ti.com.cn/wirelessconnectivity	德州仪器在线技术支持社区	www.deyisupport.com

邮寄地址： 上海市浦东新区世纪大道1568 号，中建大厦32 楼邮政编码： 200122

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS62085RLTR	ACTIVE	VSON-HR	RLT	7	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD5Q	Samples
TPS62085RLTT	ACTIVE	VSON-HR	RLT	7	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD5Q	Samples
TPS62086RLTR	ACTIVE	VSON-HR	RLT	7	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD4Q	Samples
TPS62086RLTT	ACTIVE	VSON-HR	RLT	7	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD4Q	Samples
TPS62087RLTR	ACTIVE	VSON-HR	RLT	7	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD3Q	Samples
TPS62087RLTT	ACTIVE	VSON-HR	RLT	7	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PD3Q	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

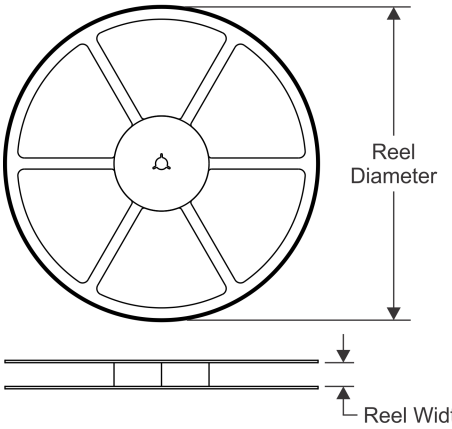
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

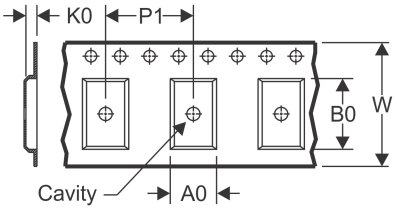
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

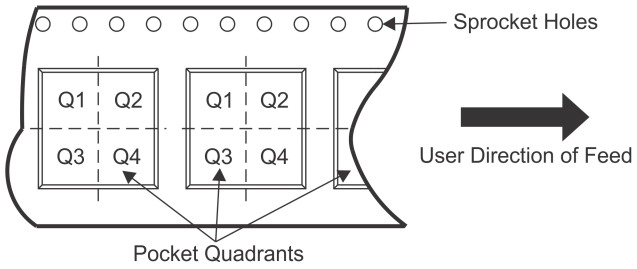


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

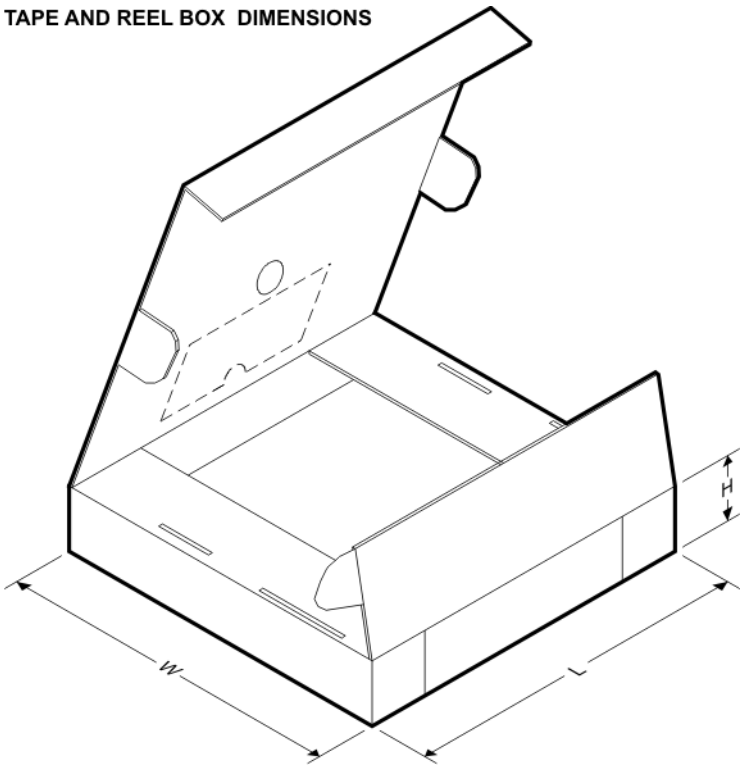
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62085RLTR	VSON-HR	RLT	7	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62085RLTT	VSON-HR	RLT	7	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62086RLTR	VSON-HR	RLT	7	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62086RLTT	VSON-HR	RLT	7	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62086RLTT	VSON-HR	RLT	7	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62087RLTR	VSON-HR	RLT	7	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62087RLTT	VSON-HR	RLT	7	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

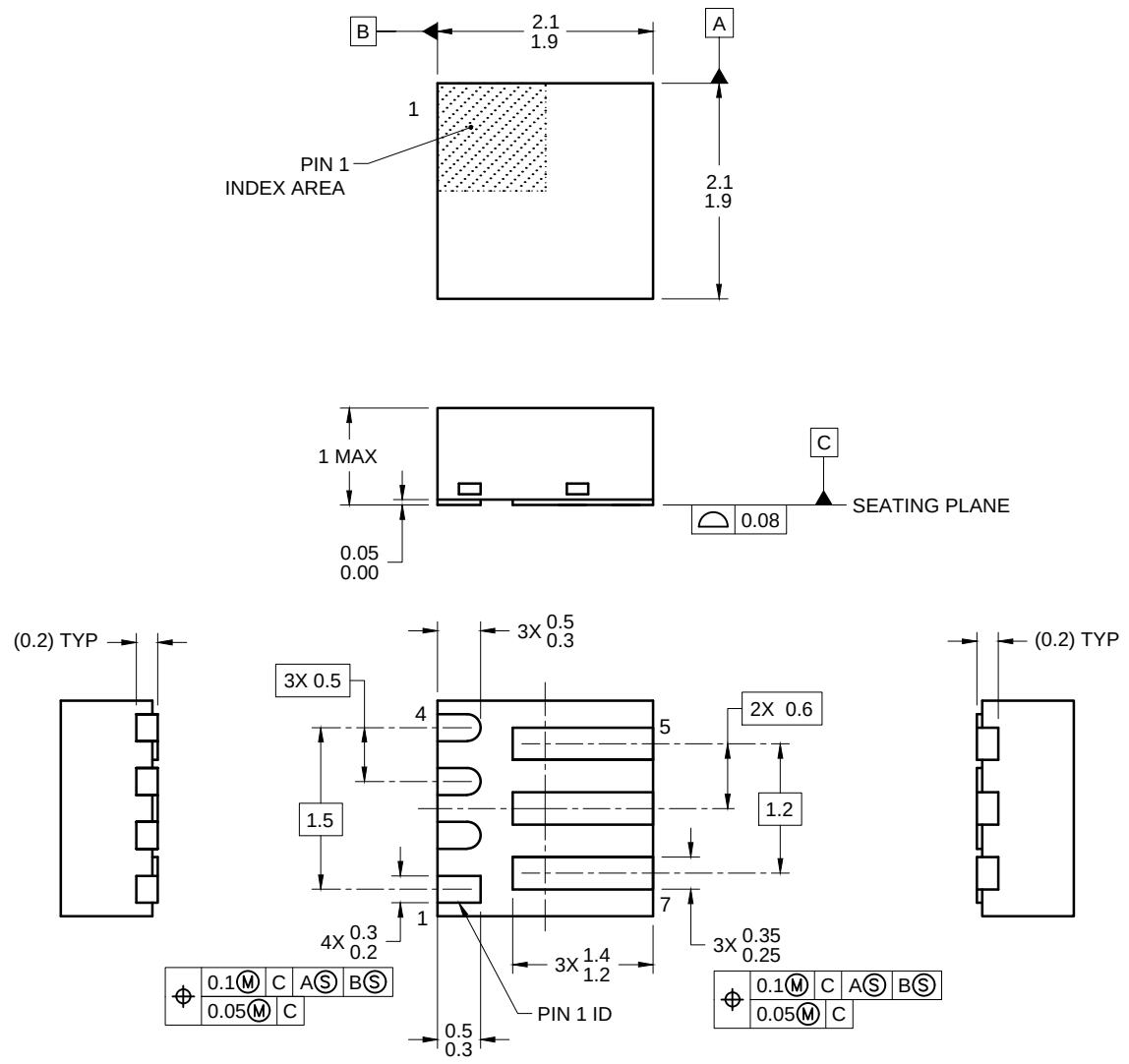
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62085RLTR	VSON-HR	RLT	7	3000	210.0	185.0	35.0
TPS62085RLTT	VSON-HR	RLT	7	250	210.0	185.0	35.0
TPS62086RLTR	VSON-HR	RLT	7	3000	210.0	185.0	35.0
TPS62086RLTT	VSON-HR	RLT	7	250	210.0	185.0	35.0
TPS62086RLTT	VSON-HR	RLT	7	250	203.0	203.0	35.0
TPS62087RLTR	VSON-HR	RLT	7	3000	210.0	185.0	35.0
TPS62087RLTT	VSON-HR	RLT	7	250	210.0	185.0	35.0

PACKAGE OUTLINE

RLT0007A

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



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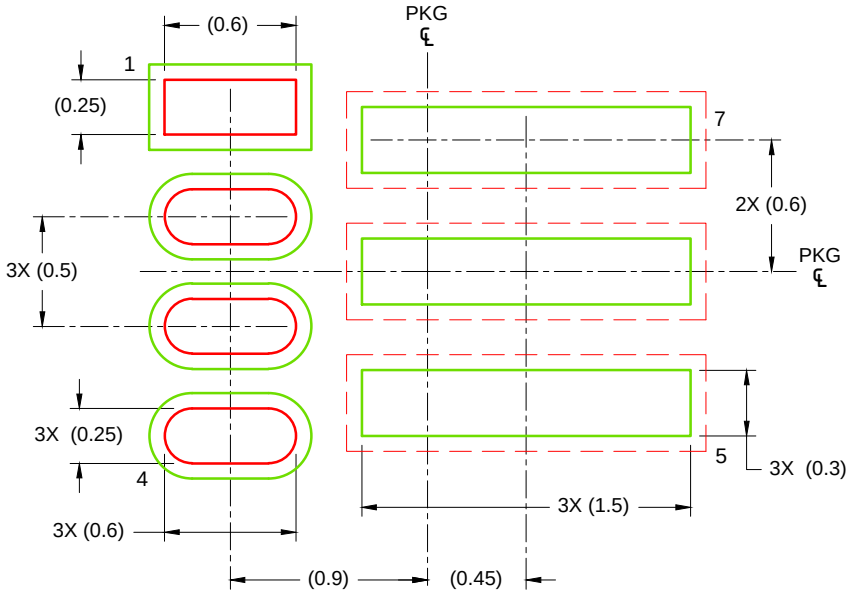
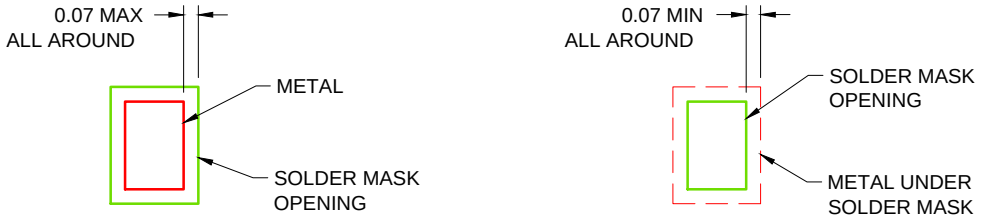
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE

SCALE: 30X



NON SOLDER MASK
DEFINED
PADS 1 - 4

SOLDER MASK
DEFINED
PADS 5 - 7

SOLDER MASK DETAILS

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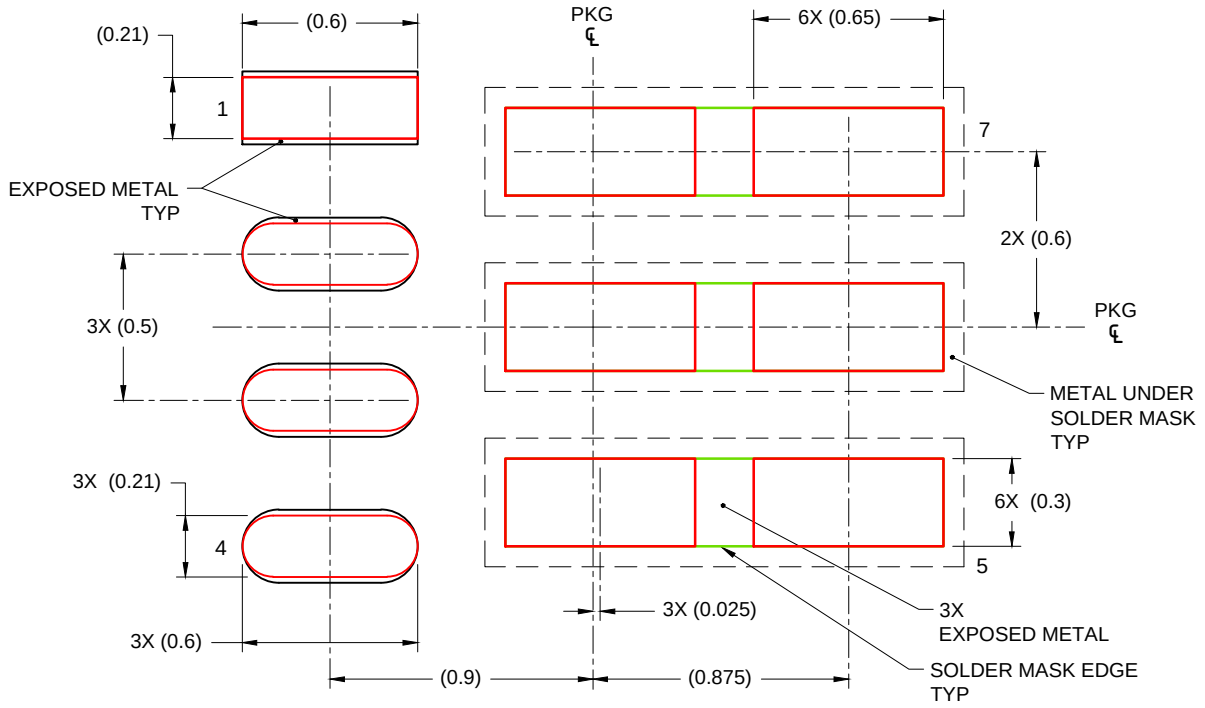
NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
5. Vias should not be placed on soldering pads unless they are plugged or plated shut.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

FOR ALL EXPOSED PADS
85% PRINTED SOLDER COVERAGE BY AREA
SCALE: 40X

4220429/A 09/2014

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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